TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# **TC74VCXH162244FT**

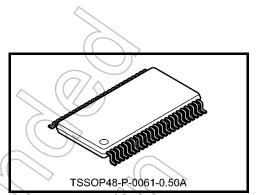
#### Low-Voltage 16-Bit Bus Buffer with Bushold

The TC74VCXH162244FT is a high-performance CMOS 16-bit bus buffer. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is non-inverting 3-state buffer having four active-low output enables. It can be used as four 4-bit buffers two 8-bit buffers or one 16-bit buffer. When the  $\overline{\rm OE}$  input is high, the outputs are in a high impedance state. This device is designed to be used with 3-state memory address drivers, etc.

The 26- $\Omega$  series resistor helps reducing output overshoot and undershoot without external resistor.

The A data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level. All inputs are equipped with protection circuits against static discharge.



Weight: 0.25 g (typ.)

#### **Features**

- 26-Ω series resistors on outputs
- Low-voltage operation: VCC = 1.8 to 3.6 V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation:  $t_{pd} = 3.3 \text{ ns (max)} (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$

 $t_{pd} = 3.8 \text{ ns (max) (VCC} = 2.3 \text{ to } 2.7 \text{ V)}$ 

:  $t_{pd} = 5.7 \text{ ns (max) (V}_{CC} = 1.8 \text{ V})$ 

• Output current:  $I_{OH}/I_{OL} = \pm 12 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$ 

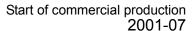
:  $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)} (V_{CC} = 2.3 \text{ V})$ 

:  $I_{OH}/I_{OL} = \pm 4 \text{ mA (min) (V}_{CC} = 1.8 \text{ V)}$ 

- Latch-up performance: -300 mA
- ESD performance: Machine model ≥ ±200 V

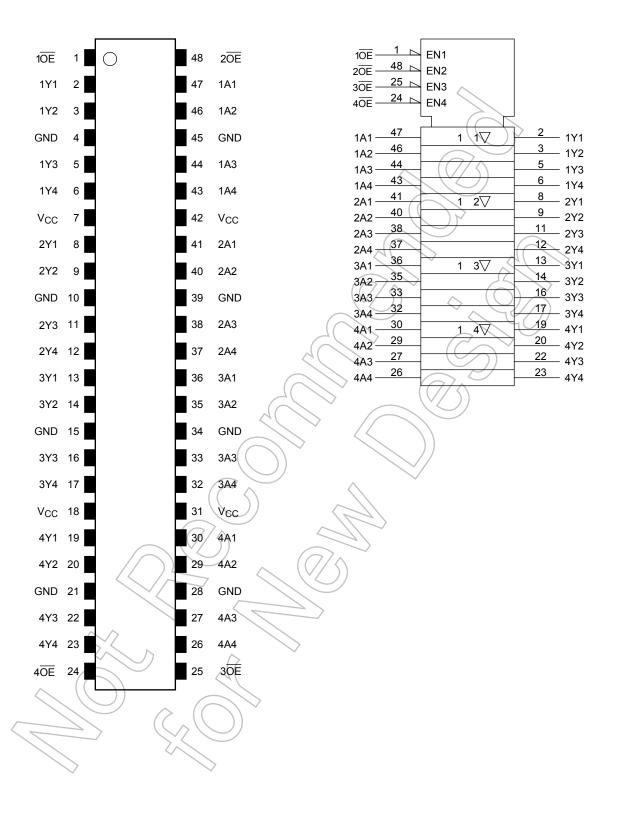
Human body model ≥ ±2000 V

- Package: TSSOP
- 3.6-V tolerant function and power-down protection control inputs and outputs



#### Pin Assignment (top view)

## **IEC Logic Symbol**



## **Truth Table**

Inp	uts	Outputs
1 <del>OE</del>	1A1-1A4	1Y1-1Y4
L	L	L
L	Н	Н
Н	Х	Z

Inp	uts	Outputs
2 <del>OE</del>	2A1-2A4	2Y1-2Y4
L	L	L
L	Н	Н
Н	Х	Z

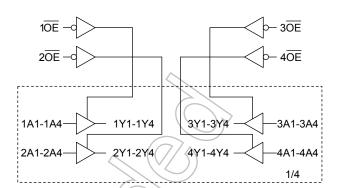
Inp	uts	Outputs
3 <del>OE</del>	3A1-3A4	3Y1-3Y4
L	L	L
L	Н	Н
Н	Х	Z

Inp	uts	Outputs
4 <del>OE</del>	4A1-4A4	4Y1-4Y4
L	L	L
L	Н	Н
Н	Х	z (

X: Don't care

Z: High impedance

## **System Diagram**



#### **Absolute Maximum Ratings (Note 1)**

Characteristics		Symbol	Rating	Unit
Power supply voltage		V <sub>CC</sub>	−0.5 to 4.6	V
DC input voltage	( OE )	V <sub>IN</sub>	-0.5 to 4.6	V
DC Input voltage	(An)	۷IN	-0.5 to V <sub>CC</sub> + 0.5	V 4
DC output voltage		Vout	-0.5 to 4.6 (Note 2)	V
DC output voltage		V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5 (Note 3)	
Input diode current		lικ	-50	mA
Output diode current		I <sub>OK</sub>	±50 (Note 4)	(mA)
Output current		lout	±50	mA
Power dissipation		P <sub>D</sub>	400	mW
DC V <sub>CC</sub> /ground current per supply pin		I <sub>CC</sub> /I <sub>GND</sub>	±100	> mA
Storage temperature		T <sub>stg</sub>	-65 to 150	°C <

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc



## **Operating Ranges (Note 1) (Note 2)**

Characteristics		Characteristics Symbol Ra		Unit	
Deviar avealusella ra		V <sub>CC</sub>	1.8 to 3.6	V	
Power supply voltage		v CC	1.2 to 3.6 (Note 3)	V	
Input voltage	( OE )	V	-0.3 to 3.6	V	
Input voltage	(An)	V <sub>IN</sub>	0 to V <sub>CC</sub>	V	
Output voltage			0 to 3.6 (Note 4)	V	
Output voltage		V <sub>OUT</sub>	0 to V <sub>CC</sub> (Note 5)	v (	
	Output current		±12 (Note 6)		
Output current			±8 (Note 7)	mA	
			±4 (Note 8)	$(\bigcirc)$	
Operating temperature		T <sub>opr</sub>	-40 to 85	,c	
Input rise and fall time		dt/dv	0 to 10 (Note 9)	ns/V	

- Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V<sub>CC</sub> or GND.
- Note 2: Floating or unused control inputs must be held high or low.
- Note 3: Data retention
- Note 4: OFF state
- Note 5: High or low state
- Note 6:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
- Note 7:  $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
- Note 8:  $V_{CC} = 1.8 \text{ V}$
- Note 9:  $V_{IN} = 0.8 \text{ to } 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

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#### **Electrical Characteristics**

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## DC Characteristics (Ta = -40 to 85°C, 2.7 V < V<sub>CC</sub> $\leq$ 3.6 V)

Characteris	stics	Symbol	Test Co	ndition	V <sub>CC</sub> (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	_	-	2.7 to 3.6	2.0	_	V
input voitage	L-level	V <sub>IL</sub>	_	_	2.7 to 3.6	_	8.0	V
				I <sub>OH</sub> = -100 μA	2.7 to 3.6	V <sub>CC</sub> - 0.2		
	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -6 \text{ mA}$	//2.7	2.2	_	
				I <sub>OH</sub> = -8 mA	3.0	2.4	_	
Output voltage				I <sub>OH</sub> = -12 mA	3.0	2.2	_	V
				$I_{OL} = 100 \mu\text{A}$	2.7 to 3.6		0.2	
	L-level	Vol	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 6 mA	2.7	*	0.4	
L-leve	L-level	VOL	AIV = AIH OL AIT	I <sub>OL</sub> = 8 mA	3.0	\$ 7/	0.5	
				I <sub>OL</sub> = 12 mA	3.0((	))~	0.8	
Input leakage	( OE )	1	V <sub>IN</sub> = 0 to 3.6 V		2.7 to 3.6	4	±5.0	
current	(An)	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7 to 3.6	\$ <u></u>	±5.0	μΑ
Bushold input minim	um drive	1	V <sub>IN</sub> = 0.8 V		(3.0)	75	_	
hold current		I <sub>I</sub> (HOLD)	V <sub>IN</sub> = 2.0 V		3.0	-75	_	μΑ
Bushold input over-o	drive current			(Note 1)	3.6	_	450	
to change state		I <sub>I (OD)</sub>	4()	(Note 2)	3.6	_	-450	μΑ
3-state output OFF	state current	l <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.7 to 3.6	_	±10.0	μА
Power-off leakage c	urrent	loff	V <sub>OUT</sub> = 0 to 3.6 V	^	0	_	10.0	μΑ
Out a sent auns les ess		. (	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7 to 3.6	_	20.0	^
Quiescent supply cu	rrent	Icc	V <sub>CC</sub> ≤ V <sub>OUT</sub> ≤ 3.6 V	(Note 3)	2.7 to 3.6	_	±20.0	μΑ
Increase in I <sub>CC</sub> per i	nput	Alcc	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V	3)	2.7 to 3.6	_	750	μΑ

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.



## DC Characteristics (Ta = -40 to 85°C, 2.3 V $\leq$ V<sub>CC</sub> $\leq$ 2.7 V)

Characteris	stics	Symbol	Test Co	ondition	V <sub>CC</sub> (V)	Min	Max	Unit
	H-level	V <sub>IH</sub>			2.3 to 2.7	1.6	_	
Input voltage	L-level	V <sub>IL</sub>	_		2,3 to 2.7	_	0.7	V
				$I_{OH} = -100 \mu A$	2.3 to 2.7	V <sub>CC</sub> - 0.2	_	
	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>II</sub>	I <sub>OH</sub> = -4 mA	2.3	2.0	_	
		0		I <sub>OH</sub> = -6 mA	2.3	1.8	_	
Output voltage			Io	I <sub>OH</sub> = -8 mA	(2.3)	1.7	_	V
		VoL	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 100 μA	2.3 to 2.7		0.2	
L-lev	L-level			I <sub>OL</sub> = 6 mA	2.3	_	0.4	
				I <sub>OL</sub> = 8 mA	2.3	8	0.6	
Input leakage	(OE)	l	$V_{IN} = 0$ to 3.6 V		2.3 to 2.7	77	±5.0	
current	(An)	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND	(7)	2.3 to 2.7	7	>±5.0	μΑ
Bushold input minim	um drive	1	$V_{IN} = 0.7 V$		2.3	45	) —	^
hold current		l (HOLD)	V <sub>IN</sub> = 1.6 V		2.3	45	_	μΑ
Bushold input over-o	drive current	1	~	(Note 1)	2.7	<u> </u>	300	
to change state		I <sub>I</sub> (OD)		(Note 2)	2.7	_	-300	μΑ
3-state output OFF	state current	l <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.3 to 2.7	_	±10.0	μΑ
Power-off leakage c	urrent	I <sub>OFF</sub>	V <sub>OUT</sub> = 0 to 3.6 V		0	_	10.0	μА
Quiacaent augustu su	urrant	1	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.3 to 2.7		20.0	^
Quiescent supply cu	inent	Icc	V <sub>CC</sub> ≤ V <sub>OUT</sub> ≤ 3.6 V	(Note 3)	2.3 to 2.7		±20.0	μΑ

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.





## DC Characteristics (Ta = -40 to $85^{\circ}$ C, $1.8 \text{ V} \leq \text{V}_{CC} < 2.3 \text{ V}$ )

Characteris	etics	Symbol	Test Co	ondition	V <sub>CC</sub> (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	_	_	1.8 to 2.3	0.7 × V <sub>CC</sub>	_	V
Input voltage L-level	L-level	V <sub>IL</sub>	_	_	1.8 to 2.3	_	0.2 × V <sub>CC</sub>	V
	H-level	VoH	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	1.8	VCC 0.2	_	
Output voltage				I <sub>OH</sub> = -4 mA	71,8	1.4	_	V
	L-level	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 100 μA	1.8		0.2	
L-level	L-level			I <sub>OL</sub> = 4 mA	1.8		0.3	
Input leakage	( OE )	I <sub>IN</sub>	$V_{IN} = 0$ to 3.6 V		J 1.8		±5.0	μА
current	(An)	NII	$V_{IN} = V_{CC}$ or GND		1.8	6	±5.0	μΑ
Bushold input minim	um drive	li (HOLD)	$V_{IN} = 0.36 V$		1.8	25	<u> </u>	μΑ
hold current		l (HOLD)	V <sub>IN</sub> = 1.26 V	(7/5)	1.8	-25	> _	μΑ
Bushold input over-c	drive current	I <sub>I (OD)</sub>		(Note 1)	1.8	(4)	200	μА
to change state		11 (OD)		(Note 2)	1.8		-200	μΑ
3-state output OFF s	state current	loz	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		1.8	_	±10.0	μА
Power-off leakage co	urrent	l <sub>OFF</sub>	V <sub>OUT</sub> = 0 to 3.6 V	· ((//	0		10.0	μА
Out and a second assessment		laa	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.8	_	20.0	
Quiescent supply cu	in cult	Icc	V <sub>CC</sub> ≤ V <sub>OUT</sub> ≤ 3.6 V	(Note 3)	1.8	_	±20.0	μА

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only

## AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500$ $\Omega$ ) (Note 1)

		177/				
Characteristics	Symbol	Test Condition		Min	Max	Unit
			V <sub>CC</sub> (V)			
$\rightarrow$	t		1.8	1.5	5.7	
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	$2.5 \pm 0.2$	1.0	3.8	ns
	tpnL ()		$3.3 \pm 0.3$	8.0	3.3	
	. (1)	1.8	1.5	6.7		
3-state output enable time	t <sub>pZL</sub>	Figure 1, Figure 3	$2.5 \pm 0.2$	1.0	5.1	ns
	(t <sub>pZH</sub> )	$3.3\pm0.3$	8.0	3.8		
			1.8	1.5	5.0	
3-state output disable time		Figure 1, Figure 3	$2.5\pm0.2$	1.0	4.0	ns
	t <sub>pHZ</sub>		$3.3\pm0.3$	8.0	3.6	
	•		1.8	_	0.5	
Output to output skew	t <sub>osLH</sub>	(Note 2)	$2.5\pm0.2$	_	0.5	ns
	tosHL		$3.3 \pm 0.3$	_	0.5	

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Note 1: For  $C_L = 50$  pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$ 

## Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition	۱ .	V <sub>CC</sub> (V)	Тур.	Unit
		V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V	(Note)	1.8	0.15	
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V	(Note)	2.5	0.25	V
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	(Note)	3.3	0.35	
	V <sub>OLV</sub>	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V	(Note)	1,8	-0.15	
Quiet output minimum dynamic V <sub>OI</sub>		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V	(Note)	2.5	-0.25	V
dynamic VOL		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	(Note)	3.3	-0.35	
Quiet output minimum dynamic V <sub>OH</sub>		V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V	(Note)	1.8	1.55	
	V <sub>OHV</sub>	V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V	(Note)	2.5	2.05	V
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	(Note)	3.3	2.65	

Note: Parameter guaranteed by design.

## **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance	C <sub>IN</sub>		1.8, 2.5, 3.3	6	pF
Output capacitance	CO		1.8, 2.5, 3.3	3 7	pF
Power dissipation capacitance	$C_{PD}$	$f_{IN} = 10 \text{ MHz}$	(Note) 1.8, 2.5, 3.3	3 20	pF

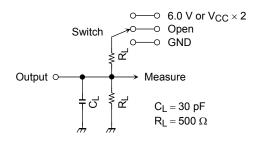
Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$ 



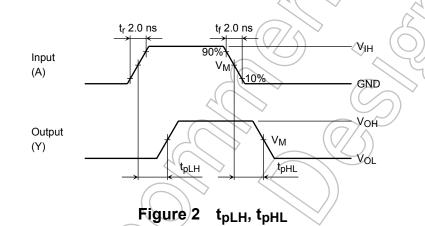
#### **AC Test Circuit**



Parameter	Switch		
t <sub>pLH</sub> , t <sub>pHL</sub>	Open		
t <sub>pLZ</sub> , t <sub>pZL</sub>	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND		

Figure 1

#### **AC Waveform**



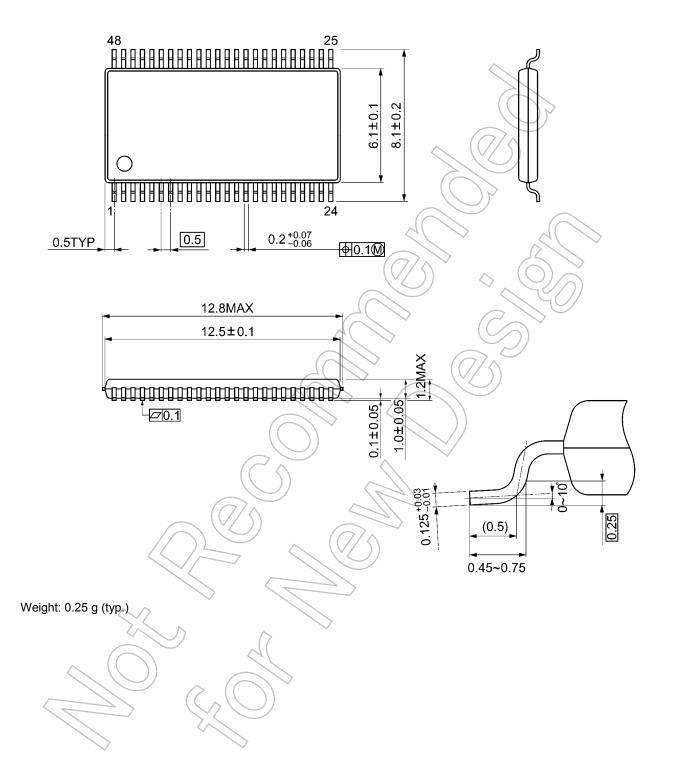
t<sub>r</sub> 2.0 ns t<sub>f</sub> 2.0 ns  $V_{\text{IH}} \\$ Output Enable Control ( $\overline{\mathsf{OE}}$ ) 10% GND  $t_{pLZ}$ 3.0 V or V<sub>CC</sub> Output (Y)  $V_{M}$ Low to Off to Low  $V_{\mathsf{OL}}$  $t_{\text{pHZ}}$  $t_{pZH}$  $V_{OH}$ Output (Y)  $V_{M}$ High to Off to High - GND Outputs enabled Outputs disabled Outputs enabled

Figure 3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$ 

Symbol	Vcc		
	$3.3\pm0.3~\textrm{V}$	2.5 ± 0.2 V	1.8 V
V <sub>IH</sub>	2.7 V	V <sub>CC</sub>	V <sub>CC</sub>
V <sub>M</sub>	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub> /2
VX	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.15 V
VY	V <sub>OH</sub> – 0.3 V	V <sub>OH</sub> – 0.15 V	V <sub>OH</sub> – 0.15 V

## **Package Dimensions**

TSSOP48-P-0061-0.50A Unit: mm



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